

## *Supporting Information*

# **Solar-responsive zinc oxide photo anode for solar- photon-harvester PEC Cell**

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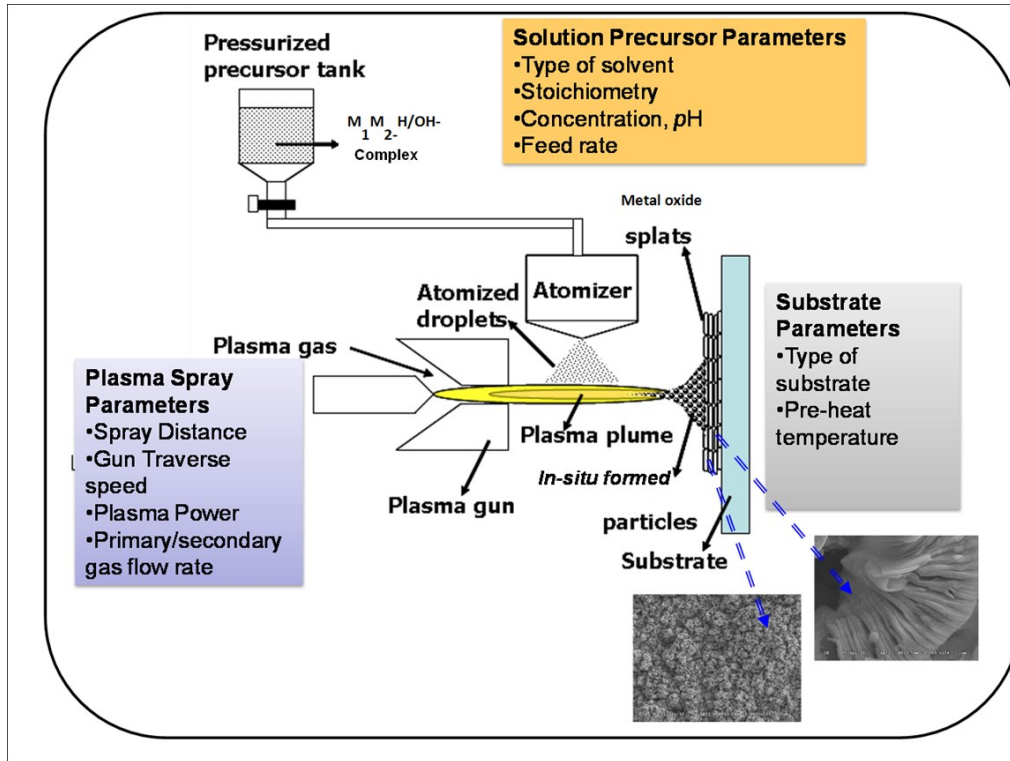
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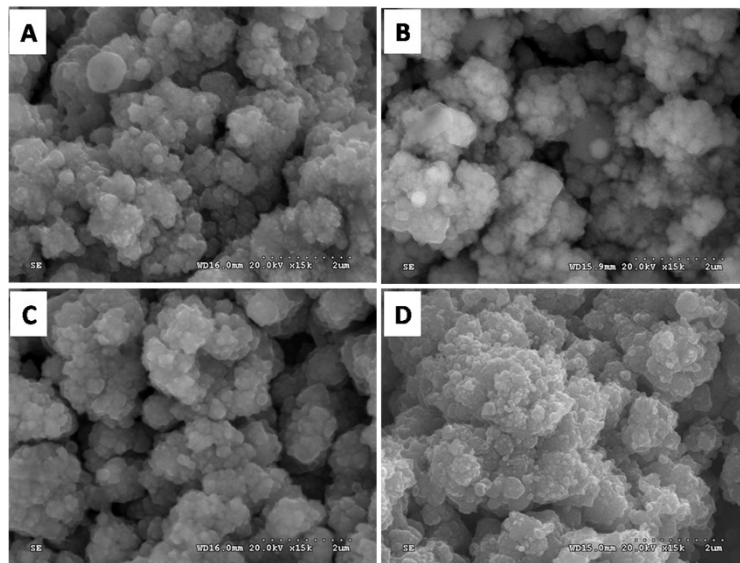
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## 1.1 SPPS deposition methodology and related parameter optimization



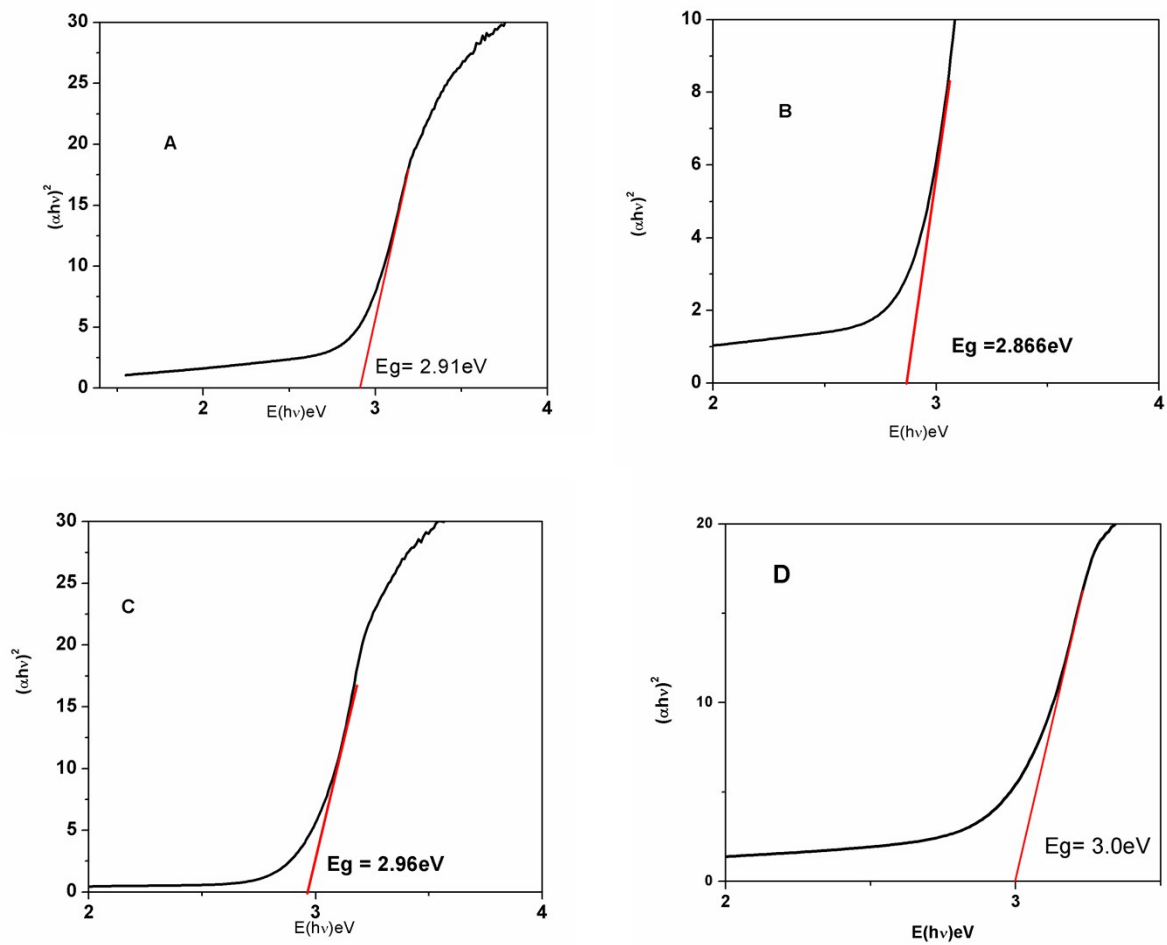
**Figure S1.** Schematic of the solution precursor plasma spray (SPPS) deposition methodology used for ZnO (SRZO) film deposition

## 1.2 Morphological studies of various ZnO films



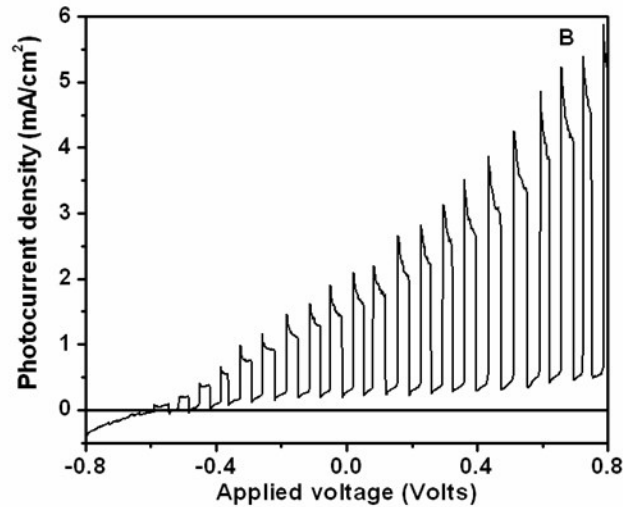
**Figure S2.** Surface morphology of the ZnO films of different thickness

### 1.3 Optical absorption studies of various ZnO films



**Figure S3.** Tauc plots of the individual ZnO films of different thickness obtained from DRS absorption spectra

### 1.4 Photo Electrochemical characterization



**Figure S4.** Chronopotential curves for ZnO film B under Hg arc lamp under light ON/OFF conditions at 0.6V biasing

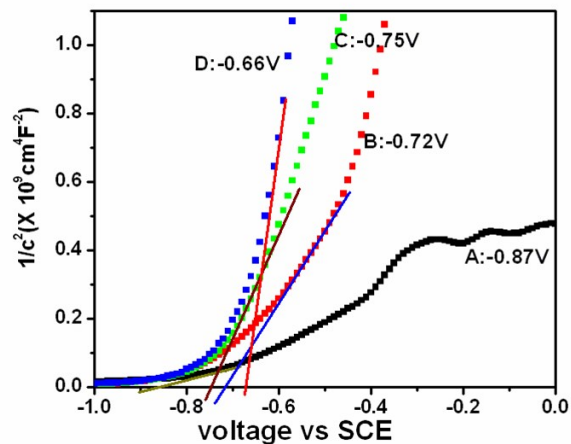
### 1.5 Incident photon to current conversion efficiency (IPCE)

IPCE is one of the most important characterizations for PEC devices. It describes the photocurrent collected per incident photon flux as a function of illumination wavelength. IPCE was calculated for different electrodes using following equation (3):

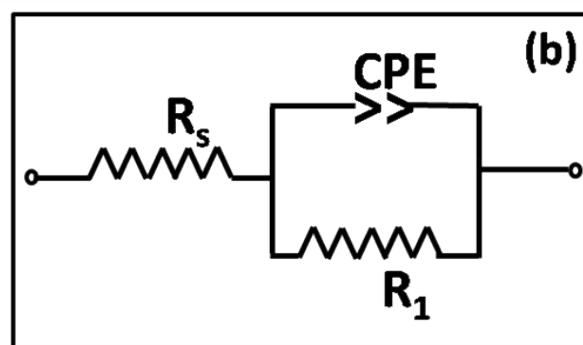
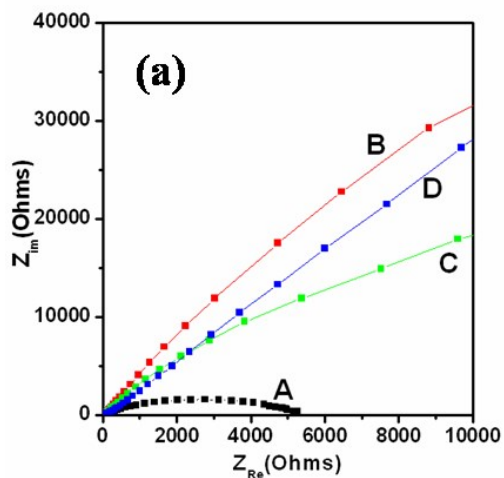
$$IPCE = \frac{1240 * J_{ph}}{P * \lambda} \dots\dots\dots (3)$$

Where  $J_{ph}$  the photocurrent density in mAcm<sup>-2</sup>, P is power of source in mWcm<sup>-2</sup> and  $\lambda$  is wavelength in nm.

## 1.6 Electrochemical impedance spectroscopy (EIS) studies on the ZnO films



**Figure S5.** M-S plots of ZnO films of different thickness under dark conditions at zero bias and an ac applied voltage of 10mv and frequency 10kz.



**Figure S6.**(a) EIS spectra of ZnO films of different thickness (b) Equivalent Randell circuit fitted using Zview software

**Table S1.** Electrochemical parameters obtained from Randell circuit using Zview software

Electrode	$R_s(\Omega)$	$R_1(\Omega)$	CPE 1-T	CPE 1-P
A	4.9	5762	0.0001114	0.611
B	11.47	174910	0.0001354	0.789
C	29.32	7345000	0.000209	0.771
D	29.7	$7.287 \times 10^{12}$	0.000057	0.710